MMBT5401L, SMMBT5401L, NSVMMBT5401L

High Voltage Transistor PNP Silicon

Features

- S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector – Emitter Voltage	V _{CEO}	-150	Vdc
Collector-Base Voltage	V _{CBO}	-160	Vdc
Emitter-Base Voltage	V _{EBO}	-5.0	Vdc
Collector Current – Continuous	Ι _C	-500	mAdc

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit	
Total Device Dissipation FR-5 Board (Note 1) $T_A = 25^{\circ}C$	P _D	225	mW	
Derate Above 25°C		1.8	mW/°C	
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	556	°C/W	
Total Device Dissipation Alumina Substrate (Note 2) $T_A = 25^{\circ}C$	P _D	300	mW	
Derate Above 25°C		2.4	mW/°C	
Thermal Resistance, Junction-to-Ambient	R_{\thetaJA}	417	°C/W	
Junction and Storage Temperature	T _J , T _{stg}	-55 to +150	°C	

1. FR-5 = $1.0 \times 0.75 \times 0.062$ in.

2. Alumina = 0.4 \times 0.3 \times 0.024 in 99.5% alumina.

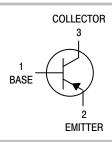


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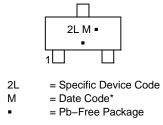
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SOT-23 (TO-236) CASE 318 STYLE 6



MARKING DIAGRAM



(Note: Microdot may be in either location)

*Date Code orientation and/or overbar may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping [†]	
MMBT5401LT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel	
SMMBT5401LT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel	
MMBT5401LT3G	SOT-23 (Pb-Free)	10,000 / Tape & Reel	
NSVMMBT5401LT3G	SOT-23 (Pb-Free)	10,000 / Tape & Reel	

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector – Emitter Breakdown Voltage $(I_{C} = -1.0 \text{ mAdc}, I_{B} = 0)$	V _{(BR)CEO}	-150	_	Vdc
Collector–Base Breakdown Voltage $(I_C = -100 \ \mu Adc, I_E = 0)$	V _{(BR)CBO}	-160	-	Vdc
Emitter – Base Breakdown Voltage $(I_E = -10 \ \mu Adc, I_C = 0)$	V _{(BR)EBO}	-5.0	_	Vdc
Collector–Base Cutoff Current $(V_{CB} = -120 \text{ Vdc}, I_E = 0)$ $(V_{CB} = -120 \text{ Vdc}, I_E = 0, T_A = 100^{\circ}\text{C})$	I _{CBO}	-	-50 -50	nAdc μAdc
ON CHARACTERISTICS				

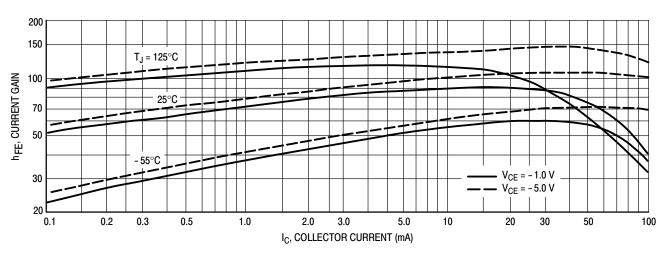
DC Current Gain	h _{FE}			-
$(I_{C} = -1.0 \text{ mAdc}, V_{CE} = -5.0 \text{ Vdc})$		50	-	
$(I_{C} = -10 \text{ mAdc}, V_{CE} = -5.0 \text{ Vdc})$		60	240	
$(I_{C} = -50 \text{ mAdc}, V_{CE} = -5.0 \text{ Vdc})$		50	-	
Collector – Emitter Saturation Voltage	V _{CE(sat)}			Vdc
$(I_{C} = -10 \text{ mAdc}, I_{B} = -1.0 \text{ mAdc})$. ,	-	-0.2	
$(I_{\rm C} = -50 \text{ mAdc}, I_{\rm B} = -5.0 \text{ mAdc})$		-	-0.5	
Base-Emitter Saturation Voltage	V _{BE(sat)}			Vdc
$(I_{C} = -10 \text{ mAdc}, I_{B} = -1.0 \text{ mAdc})$. ,	-	-1.0	
$(I_{C} = -50 \text{ mAdc}, I_{B} = -5.0 \text{ mAdc})$		-	-1.0	

SMALL-SIGNAL CHARACTERISTICS

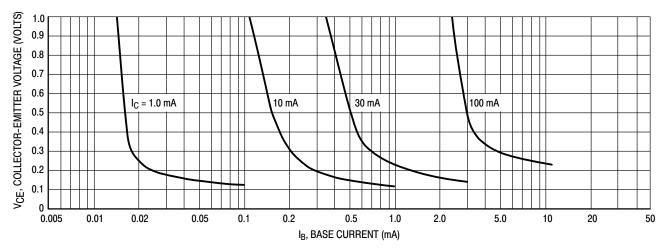
Current-Gain — Bandwidth Product ($I_C = -10 \text{ mAdc}, V_{CE} = -10 \text{ Vdc}, f = 100 \text{ MHz}$)	f _T	100	300	MHz
Output Capacitance (V _{CB} = -10 Vdc, I _E = 0, f = 1.0 MHz)	C _{obo}	_	6.0	pF
Small Signal Current Gain (I _C = -1.0 mAdc, V _{CE} = -10 Vdc, f = 1.0 kHz)	h _{fe}	40	200	-
Noise Figure (I _C = -200 μ Adc, V _{CE} = -5.0 Vdc, R _S = 10 Ω , f = 1.0 kHz)	NF	_	8.0	dB

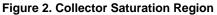
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

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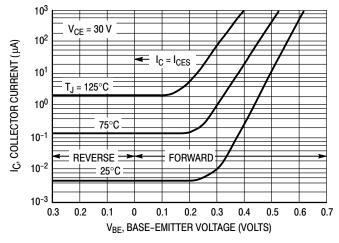
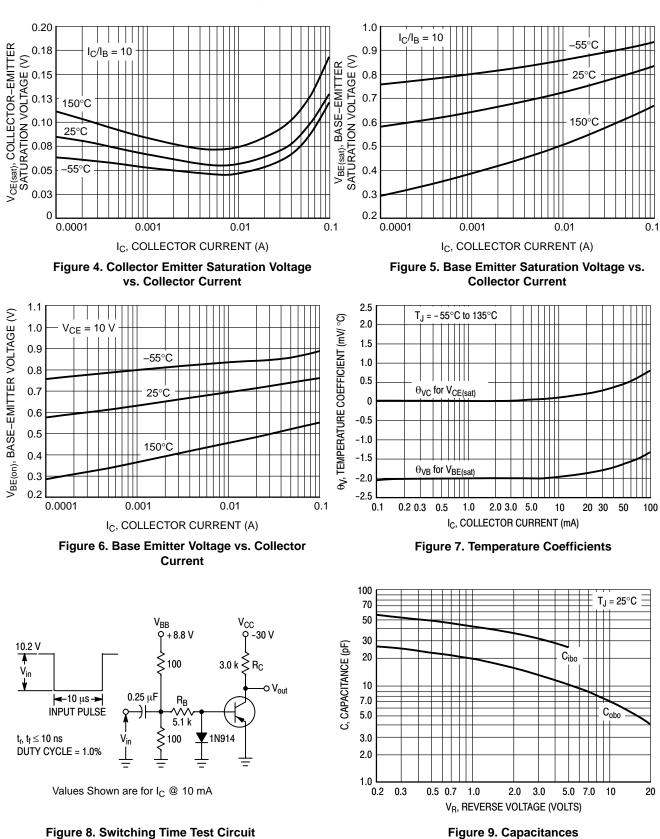
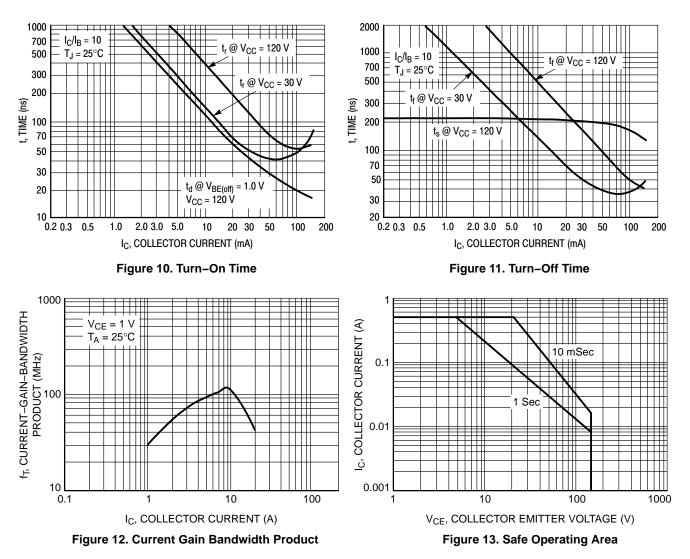


Figure 3. Collector Cut-Off Region

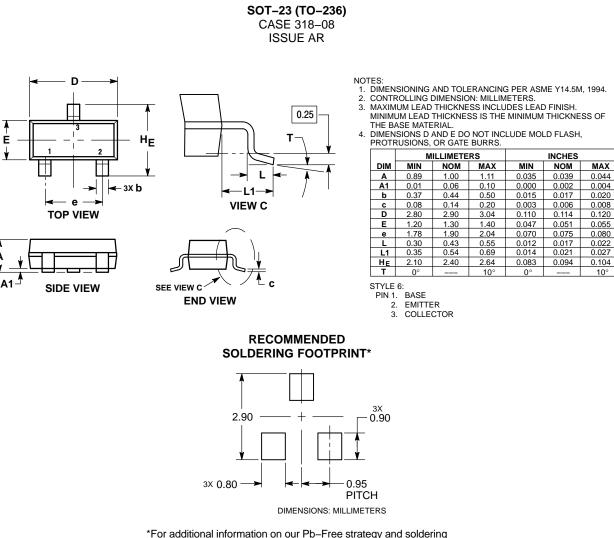
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PACKAGE DIMENSIONS



details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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